TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT   SILICON MONOLITHIC
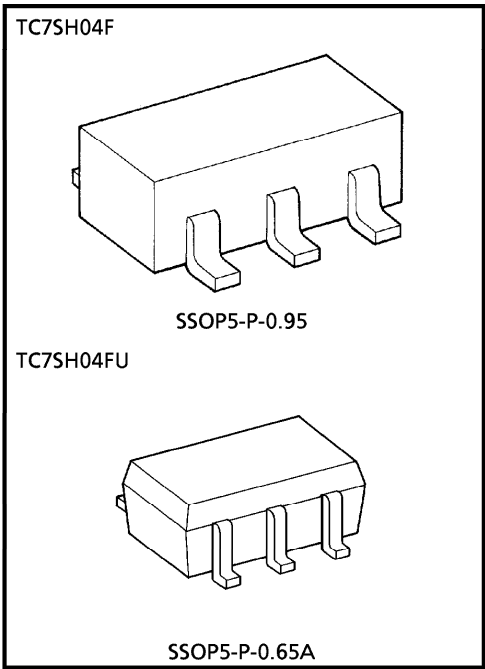
TC7SH04F, TC7SH04FU

INVERTER

The TC7SH04 is an advanced high speed CMOS INVERTER fabricated with silicon gate C²MOS technology.
It achieves The high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output. An input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interfase 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

TC7SH04F

SSOP5-P-0.95

TC7SH04FU

SSOP5-P-0.65A

Weight SSOP5-P-0.95 : 0.016g (Typ.)
SSOP5-P-0.65A : 0.006g (Typ.)

FEATURES

- High Speed ··· $t_{pd} = 3.8ns$ (Typ.) at $V_{CC} = 5V$
- Low Power Dissipation ···················· $I_{CC} = 2\mu A$ (Max.) at $Ta = 25°C$
- High Noise Immunity ···················· $V_{NIH} = V_{NIL} = 28\%\ V_{CC}$ (Min.)
- Power Down Protection is provided on all inputs.
- Balanced Propagation Delays ········· $t_{pLH} \doteqdot t_{pHL}$
- Wide Operating Voltage Range······ $V_{CC\,(opr)} = 2{\sim}5.5V$

MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	$-0.5{\sim}7.0$	V
DC Input Voltage	V_{IN}	$-0.5{\sim}7.0$	V
DC Output Voltage	V_{OUT}	$-0.5{\sim}V_{CC}+0.5$	V
Input Diode Current	I_{IK}	-20	mA
Output Diode Current	I_{OK}	± 20	mA
DC Output Current	I_{OUT}	± 25	mA
DC V_{CC}/Ground Current	I_{CC}	± 50	mA
Power Dissipation	P_D	200	mW
Storage Temperature	T_{stg}	$-65{\sim}150$	°C
Lead Temperature (10s)	T_L	260	°C

MARKING

Type Name

H 5

TRUTH TABLE

A	Y
L	H
H	L

LOGIC DIAGRAM

IN A —[1]o— OUT Y

PIN ASSIGNMENT (TOP VIEW)

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NC  [1]            [5]  VCC
IN A [2]  —|>o—    [4]  OUT Y
GND [3]            
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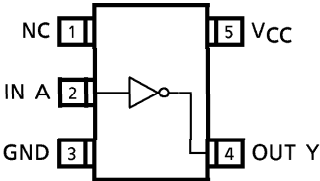
RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	2.0~5.5	V
Input Voltage	V_{IN}	0~5.5	V
Output Voltage	V_{OUT}	0~V_{CC}	V
Operating Temperature	T_{opr}	−40~85	°C
Input Rise and Fall Time	d_t / d_v	0~100 (V_{CC}=3.3±0.3V) 0~ 20 (V_{CC}=5±0.5V)	ns / V

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CIR-CUIT	TEST CONDITION		Ta = 25°C			Ta = −40~85°C		UNIT
				V_{CC}	MIN.	TYP.	MAX.	MIN.	MAX.	
High-Level Input Voltage	V_{IH}	—	—	2.0	1.50	—	—	1.50	—	V
				3.0~5.5	V_{CC}×0.7	—	—	V_{CC}×0.7	—	
Low-Level Input Voltage	V_{IL}	—	—	2.0	—	—	0.50	—	0.50	V
				3.0~5.5	—	—	V_{CC}×0.3	—	V_{CC}×0.3	
High Level Output-Voltage	V_{OH}	—	$V_{IN}=V_{IL}$, $I_{OH}=-50\mu A$	2.0	1.9	2.0	—	1.9	—	V
				3.0	2.9	3.0	—	2.9	—	
				4.5	4.4	4.5	—	4.4	—	
			$I_{OH}=-4mA$	3.0	2.58	—	—	2.48	—	
			$I_{OH}=-8mA$	4.5	3.94	—	—	3.80	—	
Low Level Output-Voltage	V_{OL}	—	$V_{IN}=V_{IH}$, $I_{OL}=50\mu A$	2.0	—	0.0	0.1	—	0.1	V
				3.0	—	0.0	0.1	—	0.1	
				4.5	—	0.0	0.1	—	0.1	
			$I_{OL}=4mA$	3.0	—	—	0.36	—	0.44	
			$I_{OL}=8mA$	4.5	—	—	0.36	—	0.44	
Input Leakage Current	I_{IN}	—	$V_{IN}=5.5V$ or GND	0~5.5	—	—	±0.1	—	±1.0	μA
Quiescent Supply Current	I_{CC}	—	$V_{IN}=V_{CC}$ or GND	5.5	—	—	2.0	—	20.0	

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3ns$)

PARAMETER	SYMBOL	TEST CIR-CUIT	TEST CONDITION			Ta = 25°C			Ta = −40~85°C		UNIT
			V_{CC} (V)	C_L (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	
Propagation Delay Time	t_{PLH} t_{PHL}	—	—	3.3 ± 0.3	15	—	5.0	7.1	1.0	8.5	ns
					50	—	7.5	10.6	1.0	12.0	
				5.0 ± 0.5	15	—	3.8	5.5	1.0	6.5	
					50	—	5.3	7.5	1.0	8.5	
Input Capacitance	C_{IN}	—	—			—	4	10	—	10	pF
Power Dissipation Capacitance	C_{PD}	—	Note (1)			—	13	—	—	—	

Note (1) : C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.
Average operating current can be obtained by the equation :

$$I_{CC\,(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

INPUT EQUIVALENT CIRCUIT
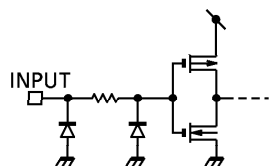
PACKAGE DIMENSIONS
   SSOP5-P-0.95   Unit : mm
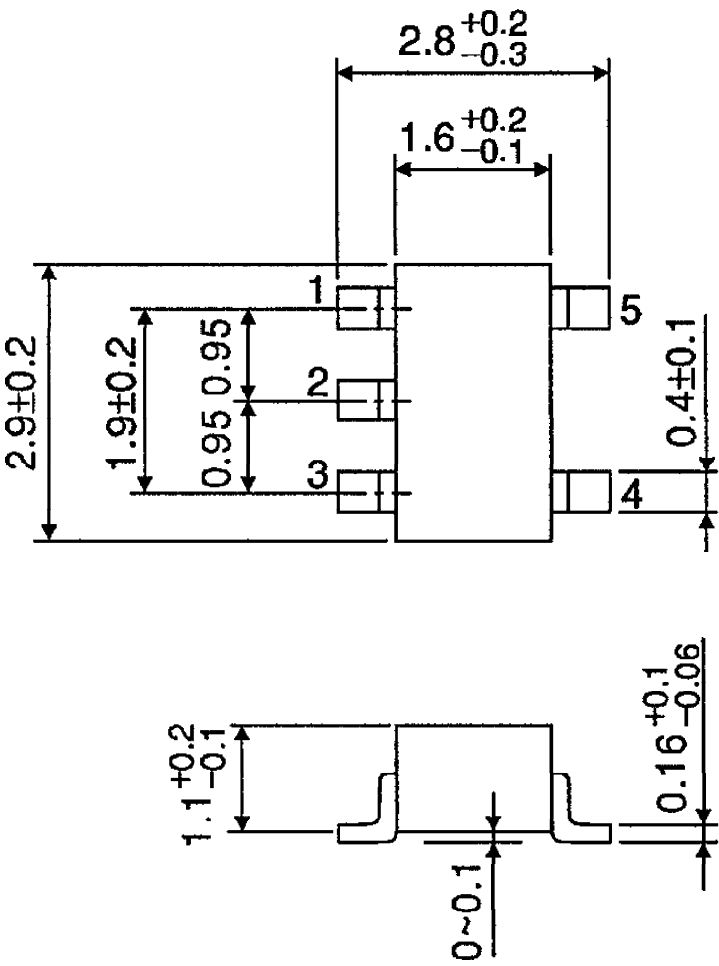
Weight : 0.016g (Typ.)

PACKAGE DIMENSIONS
SSOP5-P-0.65A   Unit : mm
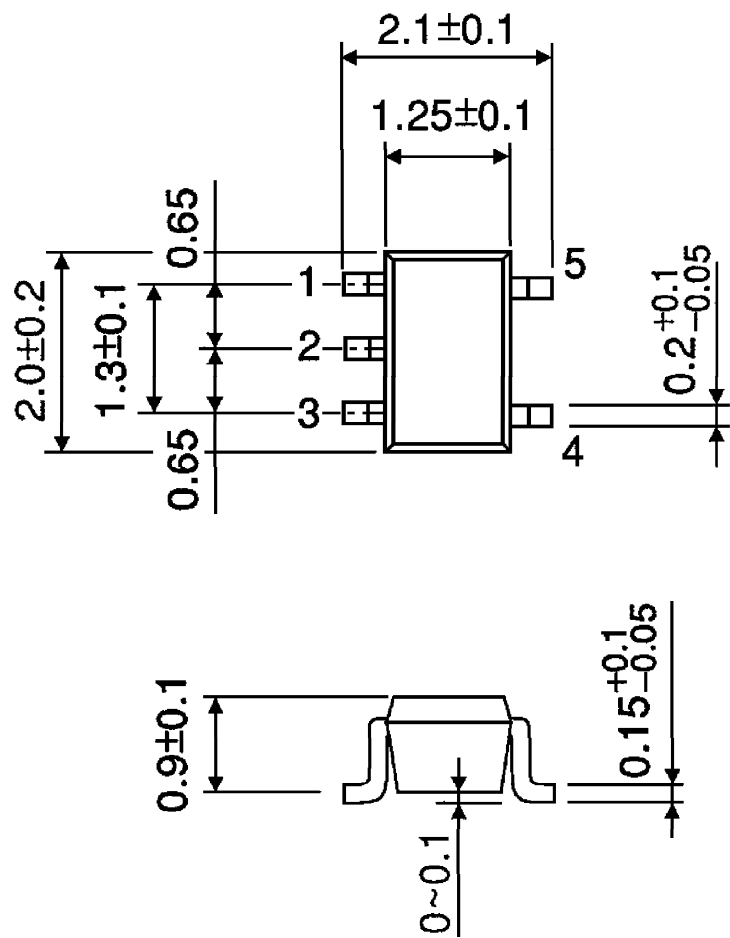
Weight : 0.006g (Typ.)

RESTRICTIONS ON PRODUCT USE

000707EBA